## SF31 THRU SF38

**Super Fast Rectifiers** Reverse Voltage - 50 to 600 V Forward Current - 3 A

#### **Features**

- · Low leakage
- · Low forward voltage
- · High current capabilit
- · Easily cleaned with alcohol, Isopropanol and similar solvents
- The plastic material carries U/L recognition 94V-0

# Φ 5.2±0.3 |Φ 1.3±0.15 25.4 MIN 25.4 MIN 8.9±0.3

**DO-201AD** 

Dimnsions in mm

#### **Mechanical Data**

· Case: JEDEC DO-201AD molded plastic body

• Terminals: Axial lead ,solderable per

MIL-STD-202, Method 208

· Polarity: Color band denotes cathode end

• Mounting Position: Any

## **Absolute Maximum Ratings and Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single-phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	SF31	SF32	SF33	SF34	SF35	SF36	SF37	SF38	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current 9.5 mm Lead Length at $T_A$ = 75 $^{\circ}$ C	I <sub>F(AV)</sub>	3								Α
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method) at $T_j$ = 125 °C	I <sub>FSM</sub>	125								А
Maximum Instantaneous Forward Voltage at 3 A	$V_{F}$	0.95 1.25 1.7				.7	V			
$ \begin{array}{ll} \text{Maximum Reverse Current} & T_{\text{A}} = 25^{\circ}\text{C} \\ \text{at Rated DC Blocking Voltage} & T_{\text{A}} = 100^{\circ}\text{C} \\ \end{array} $	I <sub>R</sub>	5 50								μA
Maximum Reverse Recovery Time 1)	t <sub>rr</sub>	35								ns
Typical Junction Capacitance 2)	CJ	100 50						pF		
Typical Thermal Resistance 3)	$R_{\theta JA}$	20							°C/W	
Operating Junction Temperature Range	Tj	- 55 to + 150							°C	
Storage Temperature Range	T <sub>stg</sub>	- 55 to + 150								°C

<sup>&</sup>lt;sup>1)</sup> Reverse recovery test conditions:  $I_F = 0.5 \text{ A}$ ,  $I_R = 1 \text{ A}$ ,  $I_{RR} = 0.25 \text{ A}$ .



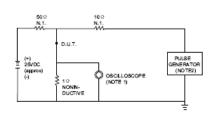




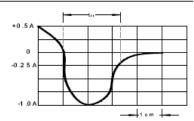
<sup>&</sup>lt;sup>2)</sup> Measured at 1 MHz and applied reverse voltage of 4 V.

<sup>&</sup>lt;sup>3)</sup> Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, P. C. B. Mounted.

#### FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



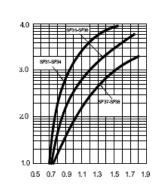
NOTES:1.RISE TIME = 7 ns MAX.IN PUT IMPEDANCE = 1M  $_{\Omega}$  .22pF. 2.RISE TIME =10ns MAX.SOURCE IMPEDANCE=50  $\,\Omega$  .



SET TIME BASE FOR 10 ns/cm

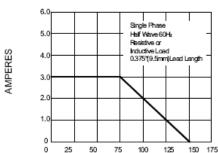
#### FIG.2 -- TYPICAL FORWARD CHARACTERISTIC





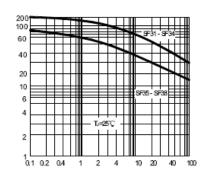
#### FIG.3 -- FORWARD DERATING CURVE





#### FIG.4 -- TYPICAL JUNCTION CAPACITANCE

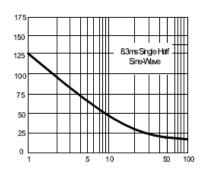
JUNCTION CAPACITANCE, pF



REVERSE VOLTAGE, VOLTS

### FIG.5 -- PEAK FORWARD SURGE CURRENT





NUMBER OF CYCLES AT 60Hz

## **TOP DYNAMIC**









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